



Canadian Association
of Physicists

Association canadienne
des physiciens et physiciennes

Contribution ID: 3822 Type: Oral Competition (Graduate Student) / Compétition orale (Étudiant(e) du 2e ou 3e cycle)

(G*) High vacuum remote plasma vapour deposition of few-layer tungsten semi-carbide

Monday 19 June 2023 14:30 (15 minutes)

High quality, uniform thin films of quantum materials are of extreme importance across many classes of device research. Minimizing energy consumption, while keeping flexibility in the deposition process, along with high structural stability, electrical and thermal conductivity, and optical transparency is critical in designing a reactor for quantum material thin film growth. Ultra-thin films based on tungsten semi-carbide (W₂C) are excellent candidates as quantum materials with startling properties such as theoretically predicted negative Poisson's ratio.[1] However, chemical-vapour thin-film deposition (CVD) techniques have not been reported to yield bona fide W₂C films, arguably because they operate under thermodynamic equilibrium conditions, where the stable phases are segregated tungsten and carbon, or the carbon-rich WC. Here, we report of the synthesis of highly crystalline few-layer W₂C, achieved using an ad-hoc designed remote plasma vapour deposition (RPVD) ultra-high vacuum reactor. The reactor built by us for this study generates tungsten ions from a 13.56 MHz radio frequency biased 2" target inductively coupled with hydrocarbon species from the ionisation of methane at ~10⁻⁶ mbar (~10⁻⁹ mbar base vacuum). The so achieved plasma is injected in a high-temperature furnace (900oC) where substrates are placed, by a 10-kV DC accelerating voltage. X-ray diffractometry, scanning tunneling microscopy, and elemental analysis have confirmed few-layer W₂C crystals in the deposits, with decreasing thickness in backstream mode deposition, with the addition of varying amounts of Ar ions in the forward gas stream. Dramatic advantages of our high-vacuum RPVD deposition system rests in the high crystallinity of our deposits, where tungsten carbides without W₂C structure (i.e. WC, or amorphous) were obtained by CVD or less advanced plasma deposition systems.[2]

[1] Wu et al, Phys. Chem. Chem. Phys., 2018, 20, 18924

[2] Baklanov et al, Mater. Res. Express, 2020, 9, 016403

Keyword-1

Tungsten carbide

Keyword-2

Two-dimensional materials

Keyword-3

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Session Classification: (DCMMP) M2-8 Low Dimensional Materials and Heterostructures | Matériaux de faible dimension et hétérostructures (DPMCM)

Track Classification: Technical Sessions / Sessions techniques: Condensed Matter and Materials Physics / Physique de la matière condensée et matériaux (DCMMP-DPMCM)